

CMOS Digital Integrated Circuits Silicon Monolithic

74VHC9151FT,74VHC9152FT

1. Functional Description

74VHC9151FT: 9-BIT SCHMITT BUFFER 74VHC9152FT: 9-BIT SCHMITT INVERTER

2. General

The 74VHC9151FT/74VHC9152FT are an ultra-high-speed 9-bit Schmitt Buffer / Inverter fabricated using silicon-gate CMOS technology. The 74VHC9151FT/74VHC9152FT combines low power consumption of CMOS with Schottky TTL speeds.

74VHC9151FT output is a non-inverting type and the 74VHC9152FT output is an inverting type.

All the inputs have hysteresis between the positive-going and negative-going thresholds. Thus the 74VHC9151FT/74VHC9152FT are capable of squaring up transitions of slowly changing input signals and provides an improved noise immunity.

Additionally, all the inputs have a newly developed protection circuit without a diode returned to V_{CC} . This enables the inputs to be tolerant of up to 5 volts even when power supply is down.

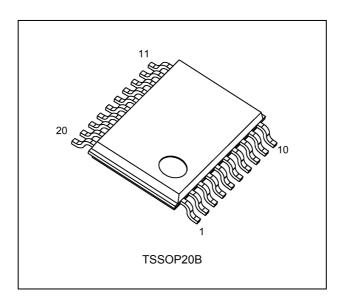
The input power-down protection capability makes the 74VHC9151FT/74VHC9152FT ideal for a wide range of applications, such as interfacing between different voltages, voltage translation from 5 V to 3 V and battery backup circuits.

3. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range: $T_{opr} = -40$ to 125 °C
- (3) High speed: $t_{pd} = 3.6 \text{ ns (typ.)}$ at $V_{CC} = 5.0 \text{ V}$
- (4) Low power dissipation: $I_{CC} = 4.0 \mu A \text{ (max)}$ at $T_a = 25 \text{ °C}$
- (5) Power down protection is provided on all inputs.
- (6) Balanced propagation delays: t_{PLH} ≈ t_{PHL}
- (7) Wide operating voltage range: $V_{CC(opr)} = 2.0 \text{ V}$ to 5.5 V

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

4. Packaging



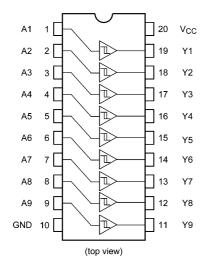
Start of commercial production

2014-06

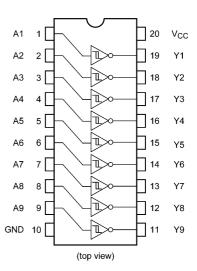


5. Pin Assignment

74VHC9151FT

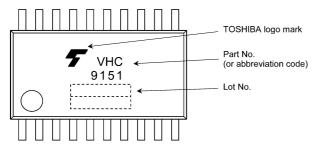


74VHC9152FT

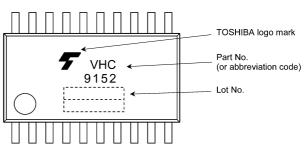


6. Marking

74VHC9151FT



74VHC9152FT



7. Truth Table

А	Y 74VHC9151FT	Y 74VHC9152FT
L	L	Н
Н	Н	L

Rev.3.0



8. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to 7.0	V
Output voltage	V _{out}		-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}		-20	mA
Output diode current	I _{OK}		±20	mA
Output current	I _{OUT}		±25	mA
V _{CC} /ground current	I _{CC}		±75	mA
Power dissipation	P _D	(Note 1)	180	mW
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: 180 mW in the range of T_a = -40 to 85 °C. From T_a = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

9. Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2.0 to 5.5	V
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 125	°C

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.



10. Electrical Characteristics

10.1. DC Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Unit
Positive threshold voltage	V _P	_		3.0	_		2.20	V
				4.5	_		3.15	
				5.5	_		3.85	
Negative threshold voltage	V _N	_		3.0	0.90		_	V
				4.5	1.35		_	
				5.5	1.65		_	
Hysteresis voltage	V _H	_		3.0	0.30		1.20	V
				4.5	0.40		1.40	
				5.5	0.50	_	1.60	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	2.0	1.9	2.0	_	V
				3.0	2.9	3.0	_	
				4.5	4.4	4.5	_	
			I _{OH} = -4 mA	3.0	2.58		_	
			I _{OH} = -8 mA	4.5	3.94	_	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	_	0.0	0.1	V
				3.0	_	0.0	0.1	
				4.5	_	0.0	0.1	
			I _{OL} = 4 mA	3.0	_	_	0.36	
			I _{OL} = 8 mA	4.5	_		0.36	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND	_	0 to 5.5	_		±0.1	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	_	4.0	μΑ

10.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Positive threshold voltage	V _P	_		3.0	_	2.20	V
				4.5	_	3.15]
				5.5	_	3.85	
Negative threshold voltage	V _N	_		3.0	0.90	_	V
				4.5	1.35	_	
				5.5	1.65	_	
Hysteresis voltage	V _H	_		3.0	0.30	1.20	V
				4.5	0.40	1.40	
				5.5	0.50	1.60	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	2.0	1.9	_	V
				3.0	2.9	_	
				4.5	4.4	_	
			$I_{OH} = -4 \text{ mA}$	3.0	2.48	_	
			I _{OH} = -8 mA	4.5	3.80	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	
			I _{OL} = 4 mA	3.0	_	0.44	
			I _{OL} = 8 mA	4.5	_	0.44	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±1.0	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	40.0	μА



10.3. DC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Condition	n	V _{CC} (V)	Min	Max	Unit
Positive threshold voltage	V _P	_		3.0	_	2.20	V
				4.5	_	3.15	
				5.5	_	3.85	
Negative threshold voltage	V _N	_		3.0	0.90	_	V
				4.5	1.35	_	
				5.5	1.65	_	
Hysteresis voltage	V _H	_		3.0	0.30	1.20	V
				4.5	0.40	1.40	
				5.5	0.50	1.60	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	2.0	1.9	_	V
				3.0	2.9	_	
				4.5	4.4	_]
			I _{OH} = -4 mA	3.0	2.40	_]
			I _{OH} = -8 mA	4.5	3.70	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	
			I _{OL} = 4 mA	3.0	_	0.55	
			I _{OL} = 8 mA	4.5	_	0.55]
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±2.0	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	80.0	μА

10.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Propagation delay time	74VHC9151FT	t _{PLH} ,t _{PHL}		_	3.3 ± 0.3	15	_	4.8	9.4	ns
						50	_	8.1	16.1	
					5.0 ± 0.5	15	_	3.3	6.0	
						50	_	5.7	10.5	
Propagation delay time	74VHC9152FT	t _{PLH} ,t _{PHL}		_	3.3 ± 0.3	15	_	4.8	9.3	ns
						50	_	7.8	15.4	
					5.0 ± 0.5	15	_	3.6	6.3	
						50	_	5.7	10.2	
Output skew		t _{osLH} ,t _{osHL}	(Note 1)	_	3.3 ± 0.3	50	_	_	1.5	ns
					5.0 ± 0.5	50	_	_	1.0	
Input capacitance		C _{IN}		_			_	4	10	pF
Power dissipation	74VHC9151FT	C _{PD}	(Note 2)	f _{IN} = 1 MHz			_	11	_	pF
capacitance	74VHC9152FT							10	_	

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/9$ (per bit)



10.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	74VHC9151FT	t_{PLH}, t_{PHL}		_	3.3 ± 0.3	15	1.0	10.7	ns
						50	1.0	18.4	
					5.0 ± 0.5	15	1.0	6.8	
						50	1.0	11.9	
Propagation delay time	74VHC9152FT	t_{PLH}, t_{PHL}		_	3.3 ± 0.3	15	1.0	10.6	ns
						50	1.0	17.6	
					5.0 ± 0.5	15	1.0	7.1	
						50	1.0	11.6	
Output skew		t_{osLH}, t_{osHL}	(Note 1)	_	3.3 ± 0.3	50		1.5	ns
					5.0 ± 0.5	50		1.0	
Input capacitance		C _{IN}		_		·	_	10	pF

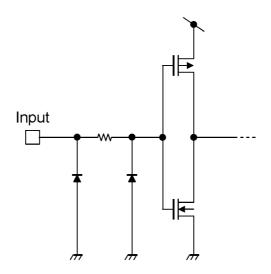
Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m - t_{PLH}n|$, $t_{osHL} = |t_{PHL}m - t_{PHL}n|$)

10.6. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	74VHC9151FT	t_{PLH}, t_{PHL}		_	3.3 ± 0.3	15	1.0	12.0	ns
						50	1.0	20.0	
					5.0 ± 0.5	15	1.0	7.5	
						50	1.0	13.0	
Propagation delay time	74VHC9152FT	t_{PLH}, t_{PHL}		_	3.3 ± 0.3	15	1.0	11.5	ns
						50	1.0	19.5	
					5.0 ± 0.5	15	1.0	8.0	
						50	1.0	13.0	
Output skew		t _{osLH} ,t _{osHL}	(Note 1)	_	3.3 ± 0.3	50	_	1.5	ns
					5.0 ± 0.5	50	1	1.0	
Input capacitance		C _{IN}		_		·	_	10	pF

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$

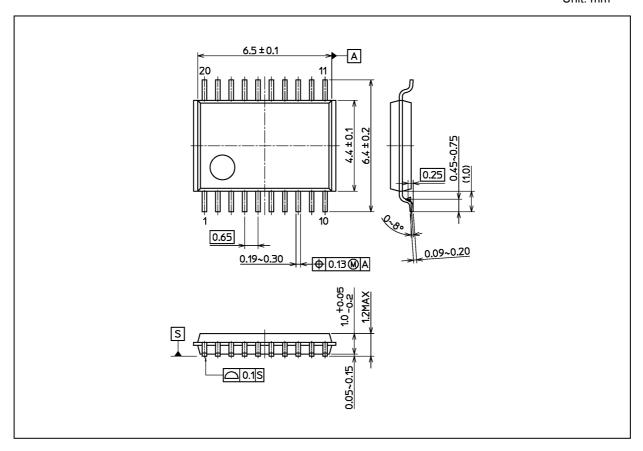
11. Internal Equivalent Circuit





Package Dimensions

Unit: mm



Weight: 0.071 g (typ.)

	Package Name(s)
Nickname: TSSOP20B	

Rev.3.0



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